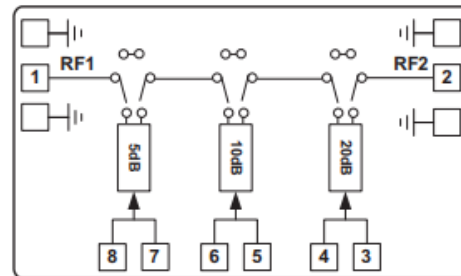


**Features**

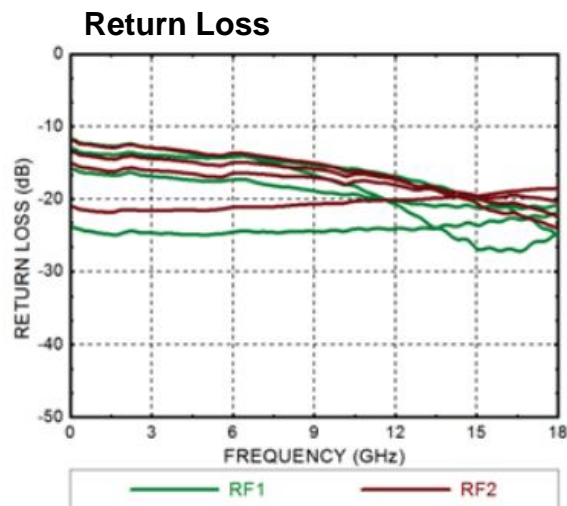
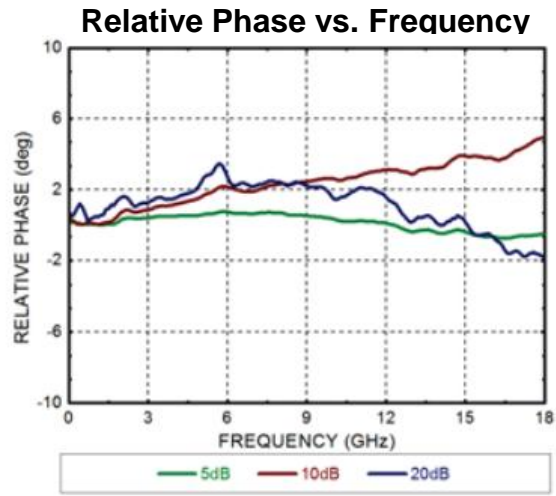
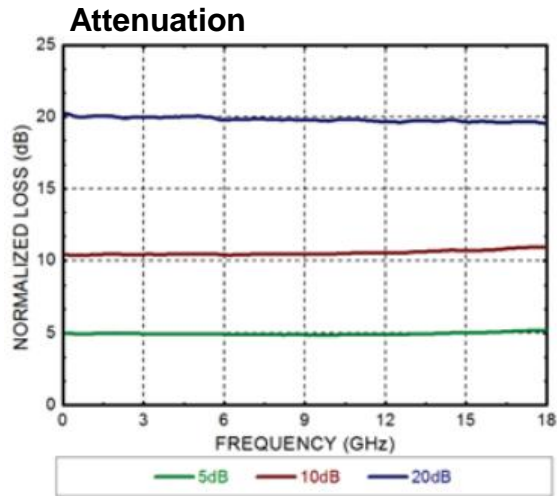
- Attenuation Range: 5dB- 35dB
- Attenuation Accuracy:  $\pm 0.2$ dB
- Insertion Loss : 4.5dB
- Attenuation Additional Phase Shift:  $\pm 6^\circ$
- Impedance: 50 $\Omega$
- Die Size: 2.0 x 1.0 x 0.1 mm

**Typical Applications**

- Test Instrumentation
- Microwave Radio & VSAT
- Military & Space
- Telecom Infrastructure
- Fiber Optics

**Functional Block Diagram**

**Electrical Specifications**
**TA = +25°C, Vctl = 0/-5V**

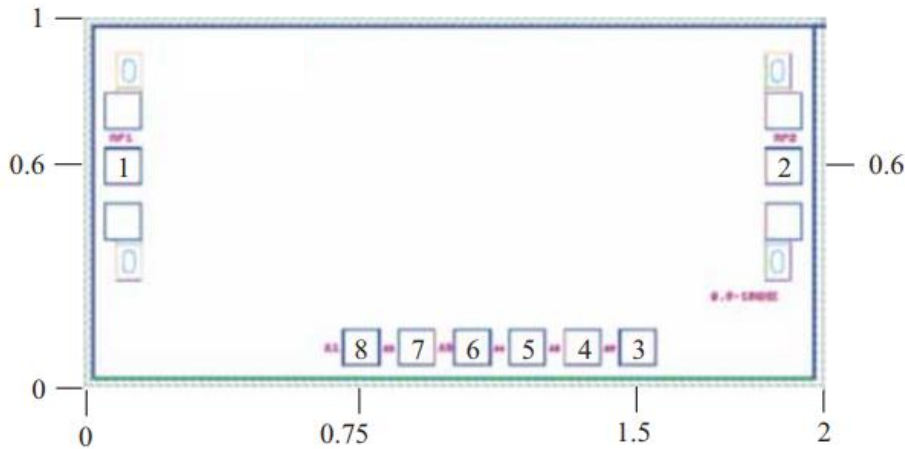
Parameters	Min.	Typ.	Max.	Units
Frequency	0.5-18			GHz
Insertion Loss		4.5		dB
Attenuation Range	5		35	dB
Return Loss (Direct State)		16		dB
Return Loss (Attenuation State)		15		dB
Input 1dB Compression (P1dB)		24		dBm
Switching Speed		30		ns





### Outline Drawing:

All Dimensions in mm

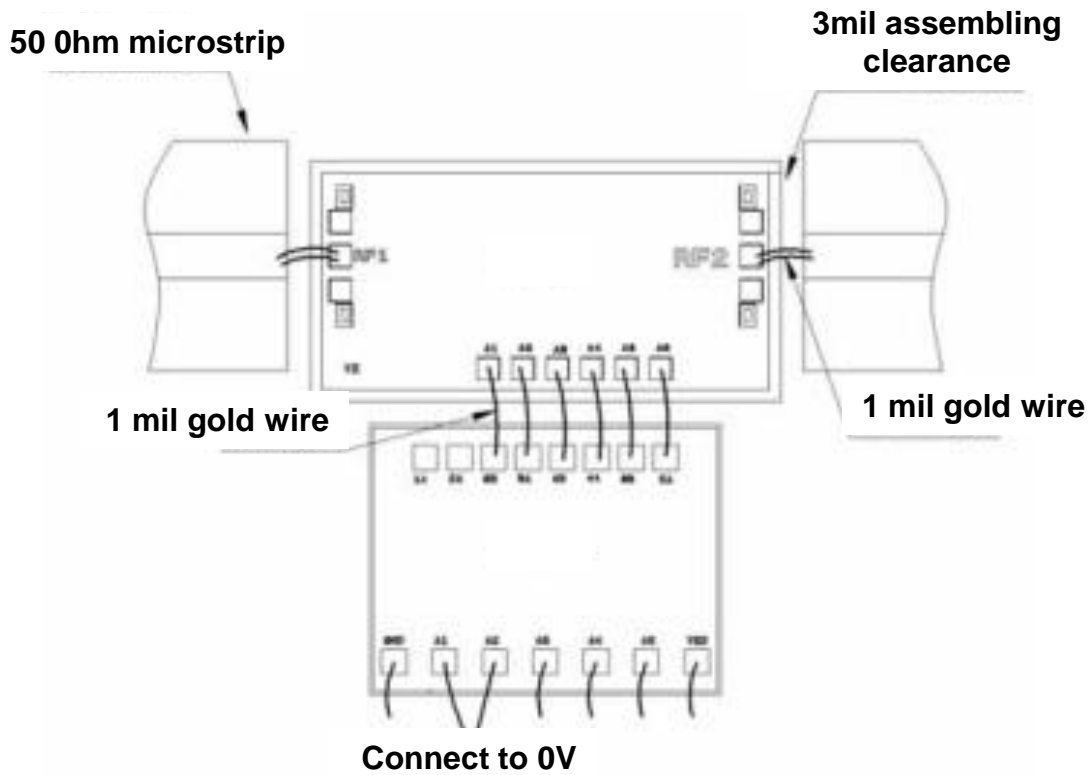


### Pad Description

PAD	Function	Description
1	RF1	This pad is RF port and matched to 50Ω Impedance
2	RF2	This pad is RF port and matched to 50Ω Impedance
3, 4	A6, A5	A 6= -5 V, A5= 0 V, pass-through ; A6=0V, A5= -5V, decaying 20dB.
5, 6	A4, A3	A 4= -5 V, A3= 0 V, pass-through ; A4=0V, A3= -5V, decaying 10dB.
7, 8	A2, A1	A 2= -5 V, A1= 0 V, pass-through ; A2=0V, A1= -5V, decaying 5dB.
Die Bottom	GND	Die bottom must be connected to RF/DC ground



### Assembly Drawing



#### Notes:

1. Die thickness: 100um
2. Typical bond pad is 100\*100  $\mu\text{m}^2$
3. Bond pad metalization: Gold
4. Backside metalization: Gold
5. Backside of the die (GND)
6. No connection required for unlabeled bond pads

#### Maximum Ratings:

1. RF input power: +24dBm
2. Storage temperature: -65°C to +175°C
3. Operating temperature: -55°C to +85°C